

### **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

# IXTH90N15T

#### FEATURES

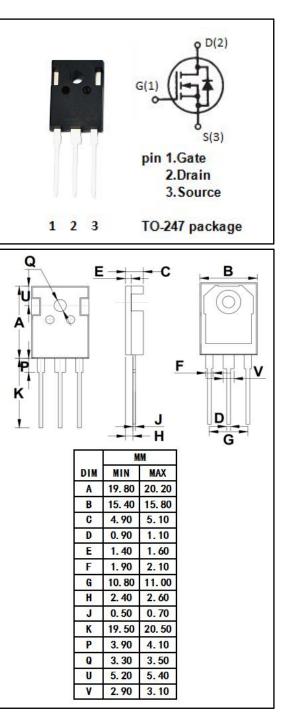
- Static drain-source on-resistance: RDs(on) ≤ 20mΩ@V<sub>GS</sub>=10V
- Fully characterized avalanche voltage and current
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATION

- DC/DC Converters
- High Speed Power Switching Applications

### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	150	v			
$V_{GS}$	Gate-Source Voltage	±30	V			
ID	Drain Current-Continuous	90	А			
Ідм	Drain Current-Single Pulsed	250	А			
P <sub>D</sub>	Total Dissipation @Tc=25℃	455	W			
Tj	Operating Junction Temperature	-55~175	°C			
T <sub>stg</sub>	Storage Temperature	-55~175	°C			
THERMAL CHARACTERISTICS						
SYMBOL	PARAMETER	МАХ	UNIT			



Junction-to-case thermal resistance

R<sub>th(j-c)</sub>

°C/W

0.33

1



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V; ID = 250 μ A	150		V
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 1mA	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 45A		20	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V		±200	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		5	μ <b>Α</b>
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 150°C		250	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 50A; V <sub>GS</sub> = 0V		1.2	V

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